

DESCRIPTION

PNP Silicon

The BC807-16L、BC807-25L and BC807-40L are available in SOT-23 package

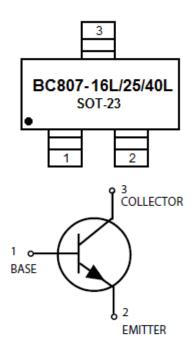
ORDERING INFORMATION

Package Type	Package Type Part Number		
SOT-23	BC807-16L		
	BC807-25L		
	BC807-40L		
Note	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

FEATURES

- Collector current capability I_C = -500mA.
- Collector-emitter voltage V_{CEO(MAX)} = -45 V
- General purpose switching and amplification
- Available in SOT-23 package

PIN DESCRIPTION



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ABSOLUTE MAXIMUM RATINGS

V _{CEO} , Collector–Emitter Voltage	-45V
V _{CBO} , Collector–Base Voltage	-50V
V _{EBO} , Emitter–Base Voltage	-5.0V
I _C , Collector Current — Continuous	-500mAdc

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	Unit
Total Device Dissipation FR- 5 BoardNOTE1			
T _A = 25°C	P_D	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	Reja	556	°C/W
Total Device Dissipation Alumina SubstrateNOTE2			
T _A = 25°C	P_{D}	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	Reja	417	°C/W
Junction and Storage Temperature	T _J , T _{STG}	-55 to +150	°C

NOTE1: FR-5 = 1.0 x 0.75 x 0.062 in.

NOTE2: Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

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ELECTRICAL CHARACTERISTICS

T_A = 25°C unless otherwise noted

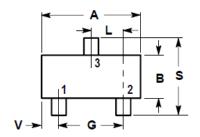
Parameter	Symbol	Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Collector–Emitter Breakdown Voltage	V _(BR) CEO	I _C = -10mA		– 45	-	-	V
Collector–Emitter Breakdown Voltage	V _{(BR)CES}	$V_{EB} = 0$, $I_C = -10\mu A$		-50	-	-	V
Emitter–Base Breakdown Voltage	V _{(BR)EBO}	I _E = -1.0 μA		-5.0	-	-	V
0.11	Ісво	V _{CB} = -20V		-	-	-100	nA
Collector Cutoff Current		V _{CB} = -20V, T _J = 150°C		-	-	-5.0	μΑ
ON CHARACTERISTICS	ON CHARACTERISTICS						
	hfE	I_{C} = -100mA, V_{CE} = -1.0V	BC807-16L	100	-	250	-
D0.0 1.0			BC807-25L	160	-	400	-
DC Current Gain			BC807-40L	250	-	600	-
		I _C = -500mA, V _{CE} = -1.0 V		40	-		-
Collector–Emitter Saturation Voltage	V _{CE(SAT)}	I _C = -500mA, I _B = -50mA		-	-	-0.7	V
Base–Emitter On Voltage	V _{BE(ON)}	I _C = -500mA, V _{CE} = -1.0 V		-	-	-1.2	V
SMALL-SIGNAL CHARACTERISTICS							
Current-Gain —	f⊤	$I_{C} = -10 \text{mA}, V_{CE} = -5.0 \text{Vdc},$ f = 100 MHz		100	_	_	MHz
Bandwidth Product	11			100		_	1911 12
Output Capacitance	Сово	V _{CB} = -10 V, f = 1.0MHz		-	10	-	pF

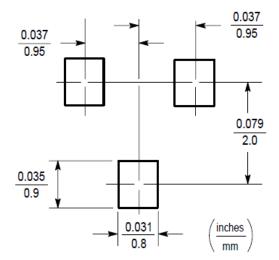
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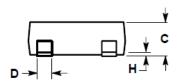


PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)









DIM	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
А	2.80	3.04	0.1102	0.1197	
В	1.20	1.40	0.0472	0.0551	
С	0.89	1.11	0.0350	0.0440	
D	0.37	0.50	0.0150	0.0200	
G	1.78	2.04	0.0701	0.0807	
Н	0.013	0.100	0.0005	0.0040	
J	0.085	0.177	0.0034	0.0070	
K	0.35	0.69	0.0140	0.0285	
L	0.89	1.02	0.0350	0.0401	
S	2.10	2.64	0.0830	0.1039	
V	0.45	0.60	0.0177	0.0236	

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